

HVC365

Variable Capacitance Diode for VCXO

HITACHI

Rev. 0
Jan. 1996

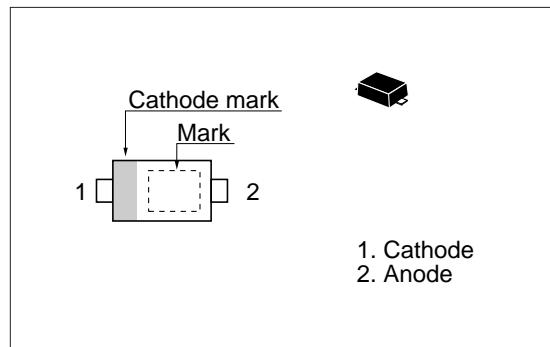
Features

- High capacitance ratio and good C-V linearity.
- To be usable at low voltage.
- Ultra small Flat Package (UFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVC365	V6	UFP

Outline



Absolute Maximum Ratings ($T_a = 25^\circ\text{C}$)

Item	Symbol	Value	Unit
Reverse voltage	V_R	15	V
Junction temperature	T_j	125	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +125	$^\circ\text{C}$

Electrical Characteristics ($T_a = 25^\circ\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	I_{R1}	—	—	10	nA	$V_R = 10\text{ V}$
	I_{R2}	—	—	100		$V_R = 10\text{ V}, T_a = 60^\circ\text{C}$
Capacitance	C_1	27.05	—	28.55	pF	$V_R = 1\text{ V}, f = 1\text{ MHz}$
	C_4	6.05	—	7.55		$V_R = 4\text{ V}, f = 1\text{ MHz}$
Capacitance ratio	n	3.0	—	—		C_1 / C_4
Series resistance	r_s	—	—	1.5	Ω	$V_R = 4\text{ V}, f = 100\text{MHz}$
ESD-Capability	—	80	—	—	V	* $C=200\text{pF}$, Both forward and reverse direction 1 pulse.

* Failure criterion : $I_R \geq 20\text{nA}$ at $V_R = 10\text{ V}$

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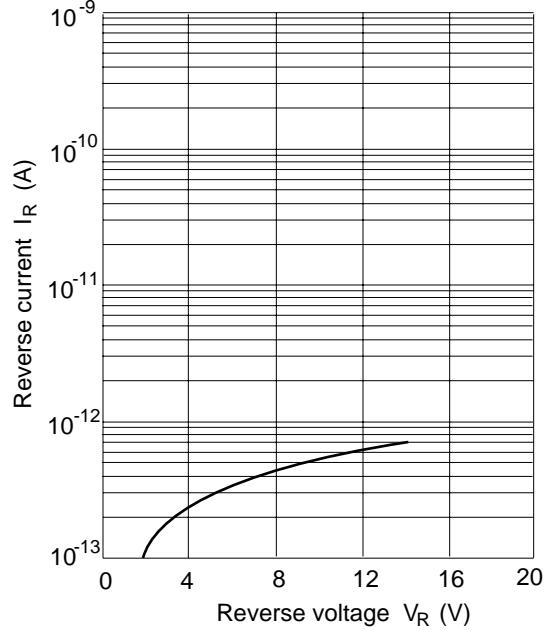


Fig.1 Reverse current Vs.
Reverse voltage

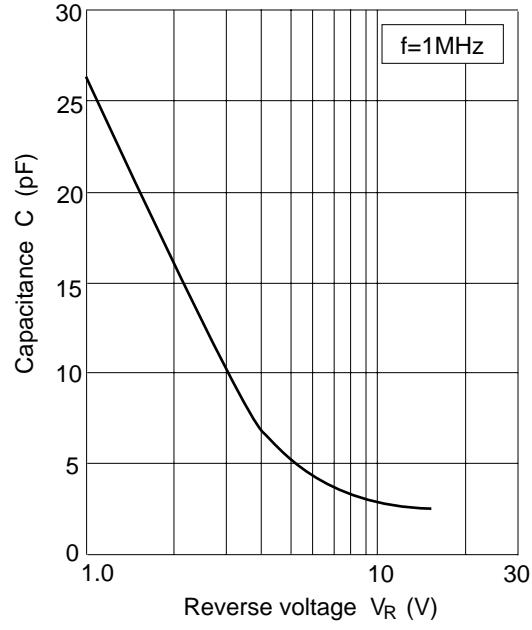
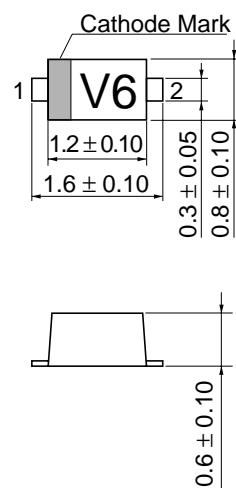


Fig.2 Capacitance Vs.
Reverse voltage

Package Dimensions

Unit: mm



- 1 Cathode
2 Anode

HITACHI Code	UFP
JEDEC Code	—
EIAJ Code	SC-79
Weight (g)	0.0016